

Notice of References Cited

Application/Control No. 09/833,372		Applicant(s)/Patent Under Reexam Wojtowicz	
Examiner B. William Baumeister	Art Unit 2815	Page 1 of 1	

U.S. PATENT DOCUMENTS

	Document Number Country Code-Number-Kind Code	Date MM-YYYY ¹	Name	Classification ²	
A	6,410,944 ✓	6/2002	Song	257	99
B	6,362,065 ✓	3/2002	Swanson et al.	438	344
C	6,320,212 ✓	11/2001	Chow	257	197
D	6,287,946 ✓	9/2001	Micovic et al.	438	571
E	5,414,273 ✓	5/1995	Shimura et al.	257	17
F	4,937,204 ✓	6/1990	Ishibashi et al.	437	110
G	4,620,206 ✓	10/1986	Ohta et al.	357	4
H	3,211,970 ✓	10/1965	Christian	317	235
I					
J					
K					
L					
M					

FOREIGN PATENT DOCUMENTS

	Document Number Country Code-Number-Kind Code	Date MM-YYYY ¹	Country	Name	Classification ²	
N	61-229361 ✓	10/1986	Japan	Oota	257	25
O	63-248164 ✓	10/1988	Japan	Kusano et al.	257	23
P	6-61245 ✓	3/1994	Japan	Takahashi	H01L	21/331
Q	4-251934 ✓	9/1992	Japan	Kodama et al.	257	16
R						
S						
T						

NON-PATENT DOCUMENTS

	Include, as applicable: Author, Title, Date, Publisher, Edition or Volume, Pertinent Pages
U	IBM Technical Disclosure Bulletin NB8908128, "Modulation-Doped Superlattice Base Heterojunction Bipolar Transistor (Modhbt)," August 1989, Vol. 32, Issue 3B, pp. 128-131.
V	
W	
X	

* A copy of this reference is not being furnished with this Office action. See MPEP § 707.05(a).

¹ Dates in MM-YYYY format are publication dates.

² Classifications may be U.S. or foreign.